Intel - 5AGZME3E3H29I4N Datasheet





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Details

Product Status	Obsolete
Number of LABs/CLBs	16980
Number of Logic Elements/Cells	360000
Total RAM Bits	23946240
Number of I/O	342
Number of Gates	-
Voltage - Supply	0.82V ~ 0.88V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	780-BBGA, FCBGA
Supplier Device Package	780-HBGA (33x33)
Purchase URL	https://www.e-xfl.com/product-detail/intel/5agzme3e3h29i4n

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AV-51002 2017.02.10

1-5

Symbol	Description	Condition	Minimum ⁽¹⁾	Typical	Maximum ⁽¹⁾	Unit
V			1.07	1.1	1.13	V
V _{CC}	Core voltage power supply	-I3	1.12	1.15	1.18	V
V	Periphery circuitry, PCIe hard IP block,	-C4, -I5, -C5, -C6	1.07	1.1	1.13	V
V _{CCP}	and transceiver PCS power supply	-I3	1.12	1.15	1.18	V
		3.3 V	3.135	3.3	3.465	V
V	Configuration nine neuron cumply	3.0 V	2.85	3.0	3.15	V
V _{CCPGM}	Configuration pins power supply	2.5 V	2.375	2.5	2.625	V
		1.8 V	1.71	1.8	1.89	V
V _{CC_AUX}	Auxiliary supply	—	2.375	2.5	2.625	V
V _{CCBAT} ⁽²⁾	Battery back-up power supply	_	1.2	_	3.0	V
	(For design security volatile key register)					
		3.3 V	3.135	3.3	3.465	V
V _{CCPD} ⁽³⁾	I/O pre-driver power supply	3.0 V	2.85	3.0	3.15	V
		2.5 V	2.375	2.5	2.625	V

⁽¹⁾ The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.

(2) If you do not use the design security feature in Arria V devices, connect V_{CCBAT} to a 1.5-V, 2.5-V, or 3.0-V power supply. Arria V power-on reset (POR) circuitry monitors V_{CCBAT}. Arria V devices do not exit POR if V_{CCBAT} is not powered up.



⁽³⁾ V_{CCPD} must be 2.5 V when V_{CCIO} is 2.5, 1.8, 1.5, 1.35, 1.25, or 1.2 V. V_{CCPD} must be 3.0 V when V_{CCIO} is 3.0 V. V_{CCPD} must be 3.3 V when V_{CCIO} is 3.3 V.

			V _{CCIO} (V)												
Parameter	Symbol	Condition	1	.2	1	.5	1.	.8	2	.5	3	.0	3.	.3	Unit
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Bus-hold trip point	V _{TRIP}	_	0.3	0.9	0.375	1.125	0.68	1.07	0.7	1.7	0.8	2	0.8	2	V

OCT Calibration Accuracy Specifications

If you enable on-chip termination (OCT) calibration, calibration is automatically performed at power up for I/Os connected to the calibration block.

Table 1-8: OCT Calibration Accuracy Specifications for Arria V Devices

Calibration accuracy for the calibrated on-chip series termination (R_S OCT) and on-chip parallel termination (R_T OCT) are applicable at the moment of calibration. When process, voltage, and temperature (PVT) conditions change after calibration, the tolerance may change.

Symbol	Symbol Description Condition (V)		Ca	alibration Accura	су	Unit
Symbol			–I3, –C4	–I5, –C5	-C6	Ont
25-Ω R _S	Internal series termination with calibration (25- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2	±15	±15	±15	%
50-Ω R _S	Internal series termination with calibration (50- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2	±15	±15	±15	%
34- Ω and 40- Ω R_S	Internal series termination with calibration (34- Ω and 40- Ω setting)	V _{CCIO} = 1.5, 1.35, 1.25, 1.2	±15	±15	±15	%
48- Ω , 60- Ω , and 80- Ω R _S	Internal series termination with calibration (48- Ω , 60- Ω , and 80- Ω setting)	$V_{CCIO} = 1.2$	±15	±15	±15	%
50-Ω R _T	Internal parallel termination with calibration ($50-\Omega$ setting)	V _{CCIO} = 2.5, 1.8, 1.5, 1.2	-10 to +40	-10 to +40	-10 to +40	%
20- Ω , 30- Ω , 40- Ω ,60- Ω , and 120- Ω R _T	Internal parallel termination with calibration (20- Ω , 30- Ω , 40- Ω , 60- Ω , and 120- Ω setting)	V _{CCIO} = 1.5, 1.35, 1.25	-10 to +40	-10 to +40	-10 to +40	%



Sumbol/Description	Condition	Transceiver Speed Grade 4		Transceiver Speed Grade 6			Unit	
Symbol/Description	Condition	Min	Тур	Max	Min	Тур	Max	Unit
Inter-transceiver block transmitter channel-to- channel skew ⁽³⁹⁾	×N PMA bonded mode	_	_	500	_	_	500	ps

Table 1-24: CMU PLL Specifications for Arria V GX and SX Devices

Symbol/Description	Transceiver S	peed Grade 4	Transceiver S	peed Grade 6	Unit
Symbol/Description	Min	Мах	Min	Мах	Onit
Supported data range	611	6553.6	611	3125	Mbps
fPLL supported data range	611	3125	611	3125	Mbps

Table 1-25: Transceiver-FPGA Fabric Interface Specifications for Arria V GX and SX Devices

Symbol/Description	Transceiver Spee	ed Grade 4 and 6	Unit
Symbol/Description	Min	Мах	Unit
Interface speed (single-width mode)	25	187.5	MHz
Interface speed (double-width mode)	25	163.84	MHz

Related Information

- CTLE Response at Data Rates > 3.25 Gbps across Supported AC Gain and DC Gain on page 1-35
- CTLE Response at Data Rates \leq 3.25 Gbps across Supported AC Gain and DC Gain on page 1-36
- Arria V GT, GX, ST, and SX Device Family Pin Connection Guidelines Provides more information about the power supply connection for different data rates.



⁽³⁹⁾ This specification is only applicable to channels on one side of the device across two transceiver banks.

Transceiver Specifications for Arria V GT and ST Devices

Symbol/Description	Condition	Tran	sceiver Speed Gra	ide 3	Unit
Symbol/Description	Condition	Min	Тур	Max	Onic
Supported I/O standards	1.2 V PCML, 1.4 VPCML	1.5 V PCML, 2.5	V PCML, Differe	ential LVPECL ⁽⁴⁰⁾ ,	HCSL, and LVDS
Input frequency from REFCLK input pins	_	27		710	MHz
Rise time	Measure at ±60 mV of differential signal ⁽⁴¹⁾			400	ps
Fall time	Measure at ±60 mV of differential signal ⁽⁴¹⁾			400	ps
Duty cycle	—	45		55	%
Peak-to-peak differential input voltage	—	200		300 ⁽⁴²⁾ /2000	mV
Spread-spectrum modulating clock frequency	PCI Express (PCIe)	30		33	kHz
Spread-spectrum downspread	PCIe		0 to -0.5%		—
On-chip termination resistors	_		100		Ω
V _{ICM} (AC coupled)	—	_	1.2	—	V
V _{ICM} (DC coupled)	HCSL I/O standard for the PCIe reference clock	250		550	mV



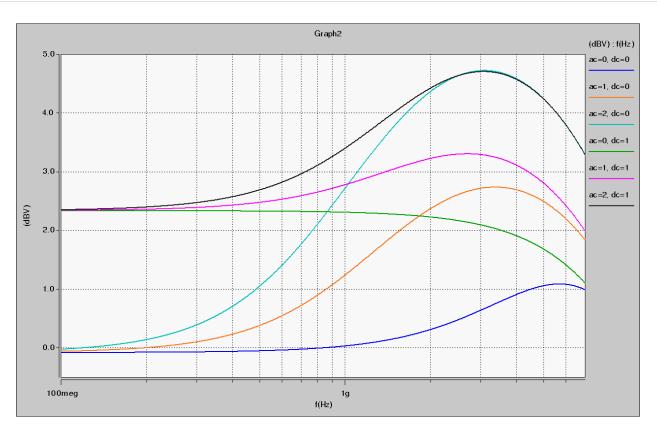
⁽⁴⁰⁾ Differential LVPECL signal levels must comply to the minimum and maximum peak-to-peak differential input voltage specified in this table.

REFCLK performance requires to meet transmitter REFCLK phase noise specification. (41)

⁽⁴²⁾ The maximum peak-to peak differential input voltage of 300 mV is allowed for DC coupled link.

CTLE Response at Data Rates > 3.25 Gbps across Supported AC Gain and DC Gain

Figure 1-2: Continuous Time-Linear Equalizer (CTLE) Response at Data Rates > 3.25 Gbps across Supported AC Gain and DC Gain for Arria V GX, GT, SX, and ST Devices

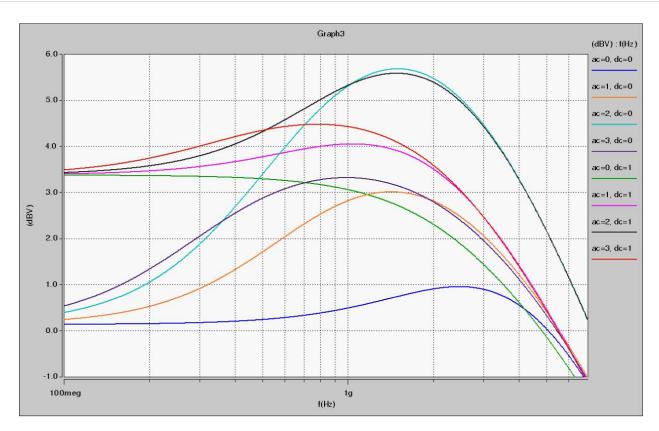


Arria V GX, GT, SX, and ST Device Datasheet



CTLE Response at Data Rates ≤ 3.25 Gbps across Supported AC Gain and DC Gain

Figure 1-3: CTLE Response at Data Rates ≤ 3.25 Gbps across Supported AC Gain and DC Gain for Arria V GX, GT, SX, and ST Devices





Symbol	Parameter	Condition	Min	Тур	Max	Unit
		-3 speed grade	_	_	670 ⁽⁶³⁾	MHz
f	Output frequency for external clock	-4 speed grade	_	_	670 ⁽⁶³⁾	MHz
f _{out_ext}	output	–5 speed grade	_	_	622 ⁽⁶³⁾	MHz
		-6 speed grade			500 ⁽⁶³⁾	MHz
t _{OUTDUTY}	Duty cycle for external clock output (when set to 50%)		45	50	55	%
t _{FCOMP}	External feedback clock compensation time	_	_	_	10	ns
t _{DYCONFIGCLK}	Dynamic configuration clock for mgmt_ clk and scanclk	_	_	_	100	MHz
t _{LOCK}	Time required to lock from end-of- device configuration or deassertion of areset	_	_		1	ms
t _{DLOCK}	Time required to lock dynamically (after switchover or reconfiguring any non-post-scale counters/delays)	_			1	ms
		Low	_	0.3	_	MHz
f _{CLBW}	PLL closed-loop bandwidth	Medium	_	1.5	_	MHz
		High ⁽⁶⁴⁾	_	4	_	MHz
t _{PLL_PSERR}	Accuracy of PLL phase shift	—	_	_	±50	ps
t _{ARESET}	Minimum pulse width on the areset signal	_	10	_	_	ns
+ (65)(66)	Input dock and to and ittar	$F_{REF} \ge 100 \text{ MHz}$	_	_	0.15	UI (p-p)
t _{INCCJ} ⁽⁶⁵⁾⁽⁶⁶⁾	Input clock cycle-to-cycle jitter	$F_{REF} < 100 \text{ MHz}$	_	_	±750	ps (p-p)

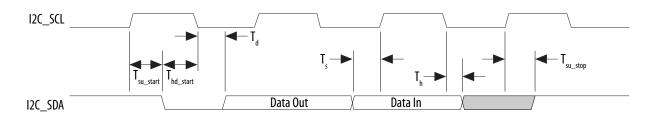
⁽⁶⁴⁾ High bandwidth PLL settings are not supported in external feedback mode.



⁽⁶⁵⁾ A high input jitter directly affects the PLL output jitter. To have low PLL output clock jitter, you must provide a clean clock source with jitter < 120 ps.

⁽⁶⁶⁾ F_{REF} is f_{IN}/N , specification applies when N = 1.

Figure 1-16: I²C Timing Diagram



NAND Timing Characteristics

Table 1-60: NAND ONFI 1.0 Timing Requirements for Arria V Devices

The NAND controller supports Open NAND FLASH Interface (ONFI) 1.0 Mode 5 timing as well as legacy NAND devices. This table lists the requirements for ONFI 1.0 mode 5 timing. The HPS NAND controller can meet this timing by programming the c4 output of the main HPS PLL and timing registers provided in the NAND controller.

Symbol	Description	Min	Max	Unit
T _{wp} ⁽⁸⁹⁾	Write enable pulse width	10	_	ns
T _{wh} ⁽⁸⁹⁾	Write enable hold time	7		ns
T _{rp} ⁽⁸⁹⁾	Read enable pulse width	10		ns
T _{reh} ⁽⁸⁹⁾	Read enable hold time	7		ns
T _{clesu} ⁽⁸⁹⁾	Command latch enable to write enable setup time	10		ns
T _{cleh} ⁽⁸⁹⁾	Command latch enable to write enable hold time	5		ns
T _{cesu} ⁽⁸⁹⁾	Chip enable to write enable setup time	15		ns
T _{ceh} ⁽⁸⁹⁾	Chip enable to write enable hold time	5		ns
T _{alesu} ⁽⁸⁹⁾	Address latch enable to write enable setup time	10		ns
T _{aleh} ⁽⁸⁹⁾	Address latch enable to write enable hold time	5		ns
T _{dsu} ⁽⁸⁹⁾	Data to write enable setup time	10		ns

⁽⁸⁹⁾ Timing of the NAND interface is controlled through the NAND configuration registers.



FPP Configuration Timing

DCLK-to-DATA[] Ratio (r) for FPP Configuration

Fast passive parallel (FPP) configuration requires a different DCLK-to-DATA[] ratio when you turn on encryption or the compression feature.

Depending on the DCLK-to-DATA[] ratio, the host must send a DCLK frequency that is r times the DATA[] rate in byte per second (Bps) or word per second (Wps). For example, in FPP $\times 16$ where the *r* is 2, the DCLK frequency must be 2 times the DATA[] rate in Wps.

Table 1-65: DCLK-to-DATA[] Ratio for Arria V Devices

Configuration Scheme	Encryption	Compression	DCLK-to-DATA[] Ratio (r)
	Off	Off	1
FPP (8-bit wide)	On	Off	1
rrr (o-on wide)	Off	On	2
	On	On	2
	Off	Off	1
EDD (16 bit wide)	On	Off	2
FPP (16-bit wide)	Off	On	4
	On	On	4

FPP Configuration Timing when DCLK-to-DATA[] = 1

When you enable decompression or the design security feature, the DCLK-to-DATA[] ratio varies for FPP ×8 and FPP ×16. For the respective DCLKto-DATA[] ratio, refer to the DCLK-to-DATA[] Ratio for Arria V Devices table.

Table 1-66: FPP Timing Parameters When DCLK-to-DATA[] Ratio is 1 for Arria V Devices

Symbol	Parameter	Minimum	Maximum	Unit
t _{CF2CD}	nCONFIG low to CONF_DONE low	_	600	ns
t _{CF2ST0}	nconfig low to nstatus low		600	ns
t _{CFG}	nCONFIG low pulse width	2	_	μs

Arria V GX, GT, SX, and ST Device Datasheet



			Active Seria	 (108)	Fast Passive Parallel ⁽¹⁰⁹⁾				
Variant	Member Code	Width	DCLK (MHz)	Minimum Configura- tion Time (ms)	Width	DCLK (MHz)	Minimum Configuration Time (ms)		
	A1	4	100	178	16	125	36		
	A3	4	100	178	16	125	36		
	A5	4	100	255	16	125	51		
Arria V GX	A7	4	100	255	16	125	51		
Allia v GA	B1	4	100	344	16	125	69		
	B3	4	100	344	16	125	69		
	B5	4	100	465	16	125	93		
	B7	4	100	465	16	125	93		
	C3	4	100	178	16	125	36		
Arria V GT	C7	4	100	255	16	125	51		
Allia v Gi	D3	4	100	344	16	125	69		
	D7	4	100	465	16	125	93		
Arria V SX	В3	4	100	465	16	125	93		
Allia V SA	B5	4	100	465	16	125	93		
Arria V ST	D3	4	100	465	16	125	93		
	D5	4	100	465	16	125	93		

Related Information Configuration Files on page 1-83

(108) DCLK frequency of 100 MHz using external CLKUSR.
 (109) Maximum FPGA FPP bandwidth may exceed bandwidth available from some external storage or control logic.

1-98 Document Revision History

Date	Version	Changes
July 2014	3.8	 Added a note in Table 3, Table 4, and Table 5: The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements. Updated V_{CC_HPS} specification in Table 5. Added a note in Table 19: Differential inputs are powered by V_{CCPD} which requires 2.5 V. Updated "Minimum differential eye opening at the receiver serial input pins" specification in Table 20 and Table 21. Updated description in "HPS PLL Specifications" section. Updated VCO range maximum specification in Table 39. Updated T_h and T_h specifications in Table 45. Added T_h specification in Table 47 and Figure 13. Updated a note in Figure 20, Figure 21, and Figure 23 as follows: Do not leave DCLK floating after configuration. DCLK is ignored after configuration is complete. It can toggle high or low if required. Removed "Remote update only in AS mode" specification in Table 58. Added DCLK device initialization clock source specification in Table 60. Added description in "Configuration Files" section: The IOCSR .rbf size is specifically for the Configuration via Protocol (CvP) feature. Removed f_{MAX_RU_CLK} specification in Table 63.
February 2014	3.7	 Updated V_{CCRSTCLK_HPS} maximum specification in Table 1. Added V_{CC_AUX_SHARED} specification in Table 1.
December 2013	3.6	 Added "HPS PLL Specifications". Added Table 24, Table 39, and Table 40. Updated Table 1, Table 3, Table 5, Table 19, Table 20, Table 21, Table 38, Table 41, Table 42, Table 43, Table 44, Table 45, Table 46, Table 47, Table 48, Table 49, Table 50, Table 51, Table 55, Table 56, and Table 59. Updated Figure 7, Figure 13, Figure 15, Figure 16, and Figure 19. Removed table: GPIO Pulse Width for Arria V Devices.



Date	Version	Changes
June 2012	2.0	 Updated for the Quartus II software v12.0 release: Restructured document. Updated "Supply Current and Power Consumption" section. Updated Table 20, Table 21, Table 24, Table 25, Table 26, Table 35, Table 39, Table 43, and Table 52. Added Table 22, Table 23, and Table 33. Added Figure 1–1 and Figure 1–2. Added "Initialization" and "Configuration Files" sections.
February 2012	1.3	 Updated Table 2–1. Updated Transceiver-FPGA Fabric Interface rows in Table 2–20. Updated V_{CCP} description.
December 2011	1.2	Updated Table 2–1 and Table 2–3.
November 2011	1.1	 Updated Table 2–1, Table 2–19, Table 2–26, and Table 2–36. Added Table 2–5. Added Figure 2–4.
August 2011	1.0	Initial release.



Symbol	Description	Conditions	Calibration Ac	Unit	
Symbol	Description	Conditions	C3, I3L	C4, I4	Onic
25-Ω R _S	Internal series termination with calibration (25- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V	±15	±15	%
50-Ω R _S	Internal series termination with calibration (50- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V	±15	±15	%
34- Ω and 40- Ω R _S	Internal series termination with calibration (34- Ω and 40- Ω setting)	V _{CCIO} = 1.5, 1.35, 1.25, 1.2 V	±15	±15	%
48-Ω, 60-Ω, 80-Ω, and 240-Ω R _S	Internal series termination with calibration (48- Ω , 60- Ω , 80- Ω , and 240- Ω setting)	$V_{CCIO} = 1.2 V$	±15	±15	%
50-Ω R _T	Internal parallel termination with calibration (50- Ω setting)	V _{CCIO} = 2.5, 1.8, 1.5, 1.2 V	-10 to +40	-10 to +40	%
20- Ω , 30- Ω , 40- Ω , 60- Ω , and 120- Ω $R_{\rm T}$	Internal parallel termination with calibration (20- Ω , 30- Ω , 40- Ω , 60- Ω , and 120- Ω setting)	V _{CCIO} = 1.5, 1.35, 1.25 V	-10 to +40	-10 to +40	%
60- Ω and 120- Ω $R_{\rm T}$	Internal parallel termination with calibration (60- Ω and 120- Ω setting)	$V_{CCIO} = 1.2$	-10 to +40	-10 to +40	%
25- $\Omega R_{S_left_shift}$	Internal left shift series termination with calibration (25- Ω R _{S_left_shift} setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V	±15	±15	%

Table 2-11: OCT Without Calibration Resistance Tolerance Specifications for Arria V GZ Devices

Symbol	Description	Conditions	Resistance	Unit	
Symbol	Description	Conditions		C4, I4	Omt
- 8	Internal series termination without calibration (25- Ω setting)	V _{CCIO} = 3.0 and 2.5 V	±40	±40	%



Hot Socketing

Table 2-14: Hot Socketing Specifications for Arria V GZ Devices

Symbol	Description	Maximum
I _{IOPIN (DC)}	DC current per I/O pin	300 µA
I _{IOPIN (AC)}	AC current per I/O pin	8 mA ⁽¹²⁴⁾
I _{XCVR-TX (DC)}	DC current per transceiver transmitter pin	100 mA
I _{XCVR-RX (DC)}	DC current per transceiver receiver pin	50 mA

Internal Weak Pull-Up Resistor

Table 2-15: Internal Weak Pull-Up Resistor for Arria V GZ Devices

All I/O pins have an option to enable the weak pull-up resistor except the configuration, test, and JTAG pins. The internal weak pull-down feature is only available for the JTAG TCK pin. The typical value for this internal weak pull-down resistor is approximately 25 k Ω .

Symbol	Description	V _{CCIO} Conditions (V) ⁽¹²⁵⁾	Value ⁽¹²⁶⁾	Unit
		3.0 ±5%	25	kΩ
		2.5 ±5%	25	kΩ
	Value of the I/O pin pull-up resistor	1.8 ±5%	25	kΩ
R_{PU}	before and during configuration, as well as user mode if you enable the programmable pull-up resistor option.	1.5 ±5%	25	kΩ
		1.35 ±5%	25	kΩ
		1.25 ±5%	25	kΩ
		1.2 ±5%	25	kΩ

⁽¹²⁴⁾ The I/O ramp rate is 10 ns or more. For ramp rates faster than 10 ns, $|I_{IOPIN}| = C dv/dt$, in which C is the I/O pin capacitance and dv/dt is the slew rate.





 $^{^{(125)}}$ The pin pull-up resistance values may be lower if an external source drives the pin higher than V_{CCIO} .

 $^{^{(126)}}$ These specifications are valid with a ±10% tolerance to cover changes over PVT.

AV-51002 2017.02.10

I/O Standard	V _{IL(D}	_{C)} (V)	V _{IH(D0}	_{_)} (V)	V _{IL(AC)} (V)	V _{IH(AC)} (V)	V _{OL} (V)	V _{OH} (V)	L (m A)	I (m A)
I/O Standard	Min	Max	Min	Max	Max	Min	Max	Min	l _{ol} (mA)	l _{oh} (mA)
SSTL-18 Class II	-0.3	V _{REF} – 0.125	V _{REF} + 0.125	V _{CCIO} + 0.3	V _{REF} – 0.25	V _{REF} + 0.25	0.28	V _{CCIO} – 0.28	13.4	-13.4
SSTL-15 Class I		V _{REF} – 0.1	V _{REF} + 0.1	_	V _{REF} – 0.175	V _{REF} + 0.175	$0.2 \times V_{ m CCIO}$	$0.8 \times V_{ m CCIO}$	8	-8
SSTL-15 Class II	_	V _{REF} – 0.1	V _{REF} + 0.1	—	V _{REF} – 0.175	V _{REF} + 0.175	$0.2 \times V_{\rm CCIO}$	$0.8 \times V_{ m CCIO}$	16	-16
SSTL-135 Class I, II		V _{REF} – 0.09	V _{REF} + 0.09	_	V _{REF} – 0.16	V _{REF} + 0.16	0.2 * V _{CCIO}	0.8 * V _{CCIO}	—	—
SSTL-125 Class I, II	_	V _{REF} – 0.85	V _{REF} + 0.85	—	V _{REF} – 0.15	V _{REF} + 0.15	0.2 * V _{CCIO}	0.8 * V _{CCIO}	—	—
SSTL-12 Class I, II	_	V _{REF} – 0.1	V _{REF} + 0.1	_	V _{REF} – 0.15	V _{REF} + 0.15	0.2 * V _{CCIO}	0.8 * V _{CCIO}	—	_
HSTL-18 Class I		V _{REF} – 0.1	V _{REF} + 0.1	_	V _{REF} - 0.2	V _{REF} + 0.2	0.4	V _{CCIO} – 0.4	8	-8
HSTL-18 Class II		V _{REF} – 0.1	V _{REF} + 0.1	_	V _{REF} - 0.2	V _{REF} + 0.2	0.4	V _{CCIO} – 0.4	16	-16
HSTL-15 Class I		V _{REF} – 0.1	V _{REF} + 0.1	_	V _{REF} – 0.2	V _{REF} + 0.2	0.4	V _{CCIO} – 0.4	8	-8
HSTL-15 Class II	_	V _{REF} – 0.1	V _{REF} + 0.1	_	V _{REF} – 0.2	V _{REF} + 0.2	0.4	V _{CCIO} – 0.4	16	-16
HSTL-12 Class I	-0.15	V _{REF} – 0.08	V _{REF} + 0.08	V _{CCIO} + 0.15	V _{REF} – 0.15	V _{REF} + 0.15	$0.25 \times V_{\rm CCIO}$	$0.75 \times V_{ m CCIO}$	8	-8
HSTL-12 Class II	-0.15	V _{REF} – 0.08	V _{REF} + 0.08	V _{CCIO} + 0.15	V _{REF} – 0.15	V _{REF} + 0.15	$0.25 \times V_{\rm CCIO}$	$0.75 \times V_{ m CCIO}$	16	-16
HSUL-12	—	V _{REF} – 0.13	V _{REF} + 0.13	—	V _{REF} – 0.22	V _{REF} + 0.22	$0.1 \times V_{\rm CCIO}$	$0.9 \times V_{ m CCIO}$	—	—

Arria V GZ Device Datasheet



Table 2-19: Differential SSTL I/O Standards for Arria V GZ Devices

I/O Standard	V _{CCIO} (V)			V _{SWIN}	V _{SWING(DC)} (V)		V _{X(AC)} (V)			V _{SWING(AC)} (V)		
	Min	Тур	Max	Min	Max	Min	Тур	Max	Min	Мах		
SSTL-2 Class I, II	2.375	2.5	2.625	0.3	V _{CCIO} + 0.6	V _{CCIO} /2 - 0.2	_	V _{CCIO} /2 + 0.2	0.62	$V_{CCIO} + 0.6$		
SSTL-18 Class I, II	1.71	1.8	1.89	0.25	V _{CCIO} + 0.6	V _{CCIO} /2 - 0.175		V _{CCIO} /2 + 0.175	0.5	V _{CCIO} + 0.6		
SSTL-15 Class I, II	1.425	1.5	1.575	0.2	(127)	V _{CCIO} /2 - 0.15		V _{CCIO} /2 + 0.15	0.35	_		
SSTL-135 Class I, II	1.283	1.35	1.45	0.2	(127)	V _{CCIO} /2 - 0.15	V _{CCIO} /2	V _{CCIO} /2 + 0.15	2(V _{IH(AC)} - V _{REF})	$2(V_{IL(AC)} - V_{REF})$		
SSTL-125 Class I, II	1.19	1.25	1.31	0.18	(127)	V _{CCIO} /2 - 0.15	V _{CCIO} /2	V _{CCIO} /2 + 0.15	2(V _{IH(AC)} - V _{REF})	_		
SSTL-12 Class I, II	1.14	1.2	1.26	0.18	—	V _{REF} -0.15	V _{CCIO} /2	V _{REF} + 0.15	-0.30	0.30		

Table 2-20: Differential HSTL and HSUL I/O Standards for Arria V GZ Devices

I/O Standard	V _{CCIO} (V)		V _{DIF(DC)} (V)		V _{X(AC)} (V)			V _{CM(DC)} (V)			V _{DIF(AC)} (V)		
	Min	Тур	Max	Min	Max	Min	Тур	Max	Min	Тур	Max	Min	Max
HSTL-18 Class I, II	1.71	1.8	1.89	0.2	_	0.78		1.12	0.78	_	1.12	0.4	_
HSTL-15 Class I, II	1.425	1.5	1.575	0.2	_	0.68		0.9	0.68	_	0.9	0.4	—



 $^{^{(127)}}$ The maximum value for $V_{SWING(DC)}$ is not defined. However, each single-ended signal needs to be within the respective single-ended limits ($V_{IH(DC)}$ and $V_{IL(DC)}$).

AV-51002 2017.02.10

Symbol/Description	Conditions	Transceiver Speed Grade 2			Transce	eiver Speed (Unit	
		Min	Тур	Max	Min	Тур	Max	Onic
	100 Hz	—	—	-70		—	-70	dBc/Hz
	1 kHz		_	-90			-90	dBc/Hz
Transmitter REFCLK Phase Noise (622 MHz) ⁽¹⁴¹⁾	10 kHz		_	-100			-100	dBc/Hz
	100 kHz		_	-110			-110	dBc/Hz
	≥1 MHz		_	-120			-120	dBc/Hz
Transmitter REFCLK Phase Jitter (100 MHz) ⁽¹⁴²⁾	10 kHz to 1.5 MHz (PCIe)		_	3			3	ps (rms)
R _{REF}	—		1800 ±1%			1800 ±1%		Ω

Related Information

Arria V Device Overview

For more information about device ordering codes.

Transceiver Clocks

Table 2-23: Transceiver Clocks Specifications for Arria V GZ Devices

Speed grades shown refer to the PMA Speed Grade in the device ordering code. The maximum data rate could be restricted by the Core/PCS speed grade. Contact your Altera Sales Representative for the maximum data rate specifications in each speed grade combination offered. For more information about device ordering codes, refer to the Arria V Device Overview.

Arria V GZ Device Datasheet



 $^{^{(141)}}$ To calculate the REFCLK phase noise requirement at frequencies other than 622 MHz, use the following formula: REFCLK phase noise at f(MHz) = REFCLK phase noise at 622 MHz + 20 *log(f/622).

⁽¹⁴²⁾ To calculate the REFCLK rms phase jitter requirement for PCIe at reference clock frequencies other than 100 MHz, use the following formula: REFCLK rms phase jitter at f(MHz) = REFCLK rms phase jitter at 100 MHz \times 100/f.

Table 2-26: CMU PLL Specifications for Arria V GZ Devices

Speed grades shown refer to the PMA Speed Grade in the device ordering code. The maximum data rate could be restricted by the Core/PCS speed grade. Contact your Altera Sales Representative for the maximum data rate specifications in each speed grade combination offered. For more information about device ordering codes, refer to the Arria V Device Overview.

Symbol/Description	Conditions	Transceiver Speed Grade 2			Transceiver Speed Grade 3			Unit
		Min	Тур	Max	Min	Тур	Мах	
Supported data range	_	600		12500	600	_	10312.5	Mbps
t _{pll_powerdown} ⁽¹⁵³⁾	_	1	_		1		—	μs
t _{pll_lock} ⁽¹⁵⁴⁾	_		—	10	_		10	μs

Related Information

Arria V Device Overview

For more information about device ordering codes.

ATX PLL

Table 2-27: ATX PLL Specifications for Arria V GZ Devices

Speed grades shown refer to the PMA Speed Grade in the device ordering code. The maximum data rate could be restricted by the Core/PCS speed grade. Contact your Altera Sales Representative for the maximum data rate specifications in each speed grade combination offered. For more information about device ordering codes, refer to the Arria V Device Overview.

Arria V GZ Device Datasheet



 $t_{pll_powerdown}$ is the PLL powerdown minimum pulse width. (153)

⁽¹⁵⁴⁾ $t_{\text{pll} \text{ lock}}$ is the time required for the transmitter CMU/ATX PLL to lock to the input reference clock frequency after coming out of reset.

t_{ARESET}

Symbol	Parameter	Min	Тур	Max	Unit
f _{out} (169)	Output frequency for an internal global or regional clock (C3, I3L speed grade)	—	—	650	MHz
	Output frequency for an internal global or regional clock (C4, I4 speed grade)	_	_	580	MHz
f _{OUT_EXT} ⁽¹⁶⁹⁾	Output frequency for an external clock output (C3, I3L speed grade)	—	—	667	MHz
	Output frequency for an external clock output (C4, I4 speed grade)	—	—	533	MHz
t _{OUTDUTY}	Duty cycle for a dedicated external clock output (when set to 50%)	45	50	55	%
t _{FCOMP}	External feedback clock compensation time	_	_	10	ns
f _{dyconfigclk}	Dynamic configuration clock for mgmt_clk and scanclk	_	_	100	MHz
t _{LOCK}	Time required to lock from the end-of-device configuration or deassertion of areset	_	_	1	ms
t _{DLOCK}	Time required to lock dynamically (after switchover or reconfiguring any non-post-scale counters/ delays)	_		1	ms
f _{CLBW}	PLL closed-loop low bandwidth	_	0.3		MHz
	PLL closed-loop medium bandwidth	_	1.5	_	MHz
	PLL closed-loop high bandwidth (170)	_	4	_	MHz
t _{PLL_PSERR}	Accuracy of PLL phase shift	—	—	±50	ps

10

_

Minimum pulse width on the areset signal





ns

 $^{^{(169)}}$ This specification is limited by the lower of the two: I/O f_{MAX} or f_{OUT} of the PLL.

⁽¹⁷⁰⁾ High bandwidth PLL settings are not supported in external feedback mode.

FPP Configuration Timing when DCLK to DATA[] > 1

Figure 2-8: FPP Configuration Timing Waveform When the DCLK-to-DATA[] Ratio is >1,

t_{CF2ST1} tcfg ;↔ nCONFIG ŤĊF2CK nSTATUS (3) 🕳 tstatus tCF2ST0 CONF_DONE (4) TCL tCH tsT2CK ŤĊF2CD (8) DCLK (6) (7) 1 2 ••• r 2 ••• r 1 \mathbf{D} (5) tCLK DATA[31..0] (8) Word 0 Word User Mode Word 3 • • • Word (n-1) tDH tDH tpsy High-Z User I/O User Mode INIT DONE (9) tCD2UM

Timing when using a MAX II device, MAX V device, or microprocessor as an external host.

Notes:

- 1. To find out the DCLK-to-DATA[] ratio for your system, refer to the "DCLK-to-DATA[] Ratio for Arria V GZ Devices" table.
- 2. The beginning of this waveform shows the device in user mode. In user mode, nCONFIG, nSTATUS, and CONF_DONE are at logic high levels. When nCONFIG is pulled low, a reconfiguration cycle begins.
- 3. After power-up, the Arria V GZ device holds nSTATUS low for the time as specified by the POR delay.
- 4. After power-up, before and during configuration, CONF_DONE is low.
- 5. Do not leave DCLK floating after configuration. DCLK is ignored after configuration is complete. It can toggle high or low if required.
- 6. "r" denotes the DCLK-to-DATA[] ratio. For the DCLK-to-DATA[] ratio based on the decompression and the design security feature enable settings, refer to the "DCLK-to-DATA[] Ratio for Arria V GZ Devices" table.
- 7. If needed, pause DCLK by holding it low. When DCLK restarts, the external host must provide data on the DATA[31.0] pins prior to sending the first DCLK rising edge.
- 8. To ensure a successful configuration, send the entire configuration data to the Arria V GZ device. CONF_DONE is released high after the Arria V GZ device receives all the configuration data successfully. After CONF_DONE goes high, send two additional falling edges on DCLK to begin initialization and enter user mode.
- 9. After the option bit to enable the INIT_DONE pin is configured into the device, the INIT_DONE goes low.



